

High efficiency preparation of $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ superconducting thin films by an acetate based Sol-Gel process

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HIGHLIGHTS

- A high-efficiency and environmentally friendly acetate based sol-gel method for Bi-2212 films is proposed.
- The whole heat treatment process only needed 4 h, which is good for environment protection and energy conservation.
- The prepared Bi-2212 superconducting films exhibit good growth textures and excellent superconductivity.

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ABSTRACT

$\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ (Bi-2212) superconducting thin films with *c*-axis epitaxial orientation were prepared on LaAlO_3 (LAO) single crystal substrates via a Sol-Gel technique using metallic acetates as starting materials. The influence of the growth temperature and oxygen partial pressure ($p\text{O}_2$) on the phase purity and superconducting properties of Bi-2212 was discussed. The results show that Bi-2212 films prepared at 820 °C with the $p\text{O}_2$ of 1.4 KPa exhibit good in-plane and out-of-plane growth textures and excellent superconducting properties with high critical transition temperature (T_c) of 88 K and narrow transition width (ΔT_c) of 4.8 K.

1. Introduction

Since the discovery of $\text{Bi}_2\text{Sr}_2\text{Ca}_n\text{Cu}_{n+1}\text{O}_8$ (BSCCO), it has been researched extensively, due to its good properties, for improving its superconductivity and structure property. Therefore, BSCCO is found to be a potential candidate for superconducting wires [1], superconducting tapes [2] and microelectronic devices [3]. In addition, BSCCO superconducting thin films have been expected to realize the application of THz technology due to its intrinsic Josephson effect [4]. In Bi-based superconductor system: Bi-2201 phase with T_c of ~24 K, Bi-2212 phase with T_c between 80 K and 96 K and Bi-2223 phase with T_c of ~110 K. Besides a good superconductivity, Bi-2212 is much more thermodynamically stable over a wide temperature than Bi-2223 phase [5]. As a consequence, Bi-2212 has attracted considerable attention for a long time. So far, Bi-2212 thin films have been prepared on single crystal substrates, Ag substrates, or MgO substrates by Pulsed Laser Deposition [6], Mechanical Exfoliation [7], Microwave Techniques [8] or Molecular Beam Epitaxy [9]. In some cases, Bi-2212 superconducting films can be produced directly from Bi-2212 powders in pure oxygen or vacuum condition [10–12]. Pb-doped Bi-2212 phase can not only lower

the heat-treatment temperature but also shorten the heat-treatment time, however, it is toxic and unfriendly to environment [13,14].

Therefore, a simple and eco-friendly method for preparing Bi-2212 thin films is urgently needed. Compared with other techniques, Sol-Gel technique has many advantages such as low cost, high efficiency, easy handling, molecular level homogeneity, environment protection and energy conservation [15–18]. So far, there are only a few reports about BSCCO superconductors prepared by Sol-Gel technique. And most of the researchers chose alkoxides or nitrates as starting materials [19–21]. As we known, alkoxides are expensive, and nitrates usually release NH_3 and NO_2 that destroy the surface quality of Bi-2212 films during the heat treatment process [22].

To avoid these problems mentioned above, *c*-axis epitaxial Bi-2212 films were prepared on LaAlO_3 (LAO) substrates by Sol-Gel method using Bi-acetate, Sr-acetate, Ca-acetate and Cu-acetate as starting materials. LAO (3.8 Å) and Bi-2212 (5.4 Å) has a small lattice mismatch of 0.49% in 45-degree rotated lattice matching relation in *a*-*b* plane, it is good for improving film growth and film quality. The effects of heat-treatment temperature and oxygen partial pressure on the quality of Bi-2212 films were investigated in detail to improve their phase purity and

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superconductivity. After optimizing heat treatment parameters, the whole heat-treatment time was shortened to 4 h.

2. Experimental procedure

2.1. Preparation of Bi-2212 films

Analytical reagent $\text{Bi}(\text{CH}_3\text{COO})_3(\text{BiAc}3)$, $\text{Sr}(\text{CH}_3\text{COO})_2 \cdot 1/2\text{H}_2\text{O}(\text{Sr}(\text{Ac})_2)$, $\text{Ca}(\text{CH}_3\text{COO})_2 \cdot \text{H}_2\text{O}(\text{Ca}(\text{Ac})_2)$ and $\text{Cu}(\text{CH}_3\text{COO})_2 \cdot \text{H}_2\text{O}(\text{Cu}(\text{Ac})_2)$, acrylic acid (AA) and methanol (MeOH) were used as starting material, chemical modifier and solvent to synthesize Bi-2212 solution. Fig. 1 shows the process for the preparation of Bi-2212 solution. BiAc_3 , $\text{Sr}(\text{Ac})_2$, $\text{Ca}(\text{Ac})_2$ and $\text{Cu}(\text{Ac})_2$ were dissolved into AA and MeOH respectively in a stoichiometric quantity of $(\text{BiAc}_3:\text{AA}:\text{MeOH} = 1:10:20)$, $(\text{Sr}(\text{Ac})_2:\text{AA}:\text{MeOH} = 1:12:20)$, $(\text{Ca}(\text{Ac})_2:\text{AA}:\text{MeOH} = 1:12:20)$ and $(\text{Cu}(\text{Ac})_2:\text{AA}:\text{MeOH} = 1:3:60)$ at room temperature to prepare Bi-solution, Sr-solution, Ca-solution and Cu-solution, respectively. Then the four solutions were mixed in the controlled stoichiometry of $\text{Bi}:\text{Sr}:\text{Ca}:\text{Cu} = 2:2:1:2$, stirred and aged for 48 h to form the stable Bi-2212 solution.

In order to investigate the effect of heat treatment temperature on phase purity of Bi-2212, four groups of Bi-2212 gel films were prepared on LAO substrates by dip-coating method and heat treated at 780 °C, 800 °C, 820 °C and 840 °C, respectively. Fig. 2 shows the heat treatment profile of Bi-2212 films. During the heat-treatment process, Bi-2212 gel films were firstly heated up to 420 °C from room temperature in humid N_2 , it is aim to exhaust air and avoid film toughing and drying. Subsequently, Bi-2212 films were heated up to 600 °C in dry O_2 , and the content of O_2 should be enough to form the intermediate phase completely at this stage. Then the Bi-2212 films were heated up to 780 °C, 800 °C, 820 °C or 840 °C and crystallized for 40 min in humid N_2 mixed with small amounts of O_2 . Oxygen content has an important effect on the phase formation of Bi-2212 during high-temperature phase formation process, and it will be discussed in detail in 3.2. Finally the Bi-2212 films were dwelled at 550 °C for 50 min in dry O_2 to fill oxygen vacancies [23]. The whole heat treatment process only needed 4 h and the high-temperature phase formation process only needed 40 min.

2.2. Characterization

A SmartLab X-ray diffractometer in θ - 2θ , ω and φ scan modes (XRD) is used to determine the phases, the out-of-plane texture, and the in-

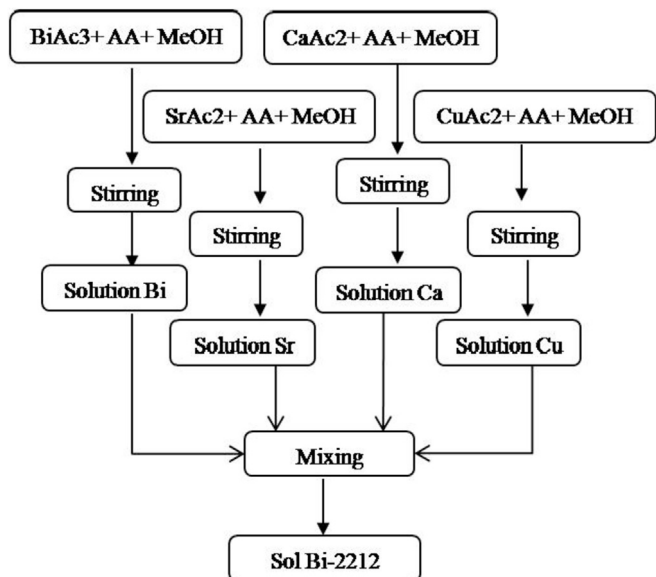


Fig. 1. Flowchart for the preparation of Bi-2212 Solution.

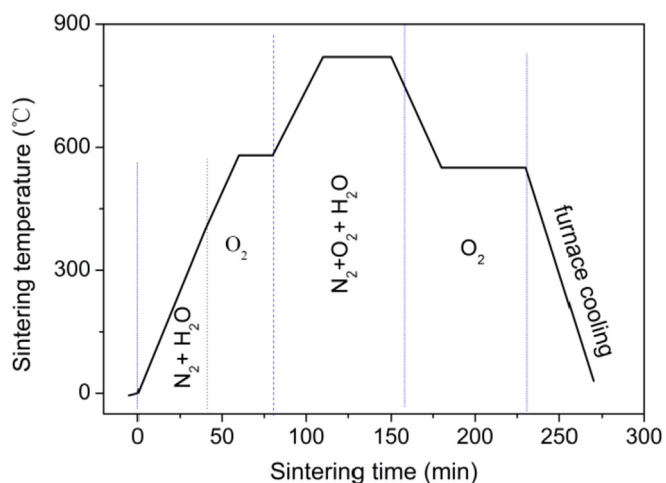


Fig. 2. Profile for the heat treatment of Bi-2212 thin films.

plane texture, respectively. Scanning electron microscopy (SEM) experiments are conducted on a JEM-6700F and energy dispersive spectrometry (EDS) was adopted to detect the composition of the films. Curves depicting the resistance-temperature (R - T) characteristics of the films were measured by A VersaLab multi-function vibrating sample magnetometer (VSM).

3. Results and discussion

3.1. The effect of heat treatment temperature on phase purity of Bi-2212

Fig. 3 shows XRD patterns of the Bi-2212 films heat-treated at 600 °C. As seen, Bi_2O_3 , SrO , CaO , CuO , CaSrCuO_3 and $\text{Bi}_2\text{Sr}_3\text{Cu}_2\text{O}_8$ were detected, indicating that the acetates have been decomposed to form the above oxides and then the oxides interreacted with each other to yield some other intermediate products at 600 °C. The related chemical reactions are represented in equations (1)–(6).

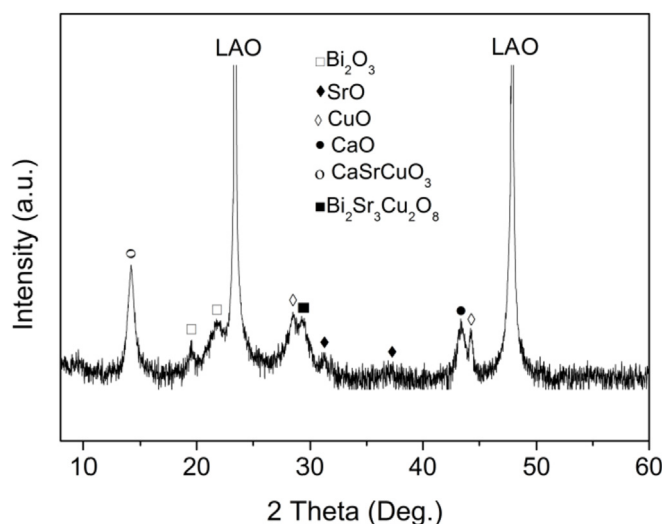
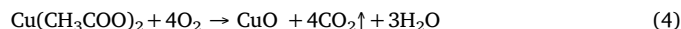
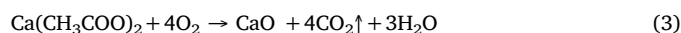
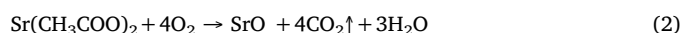
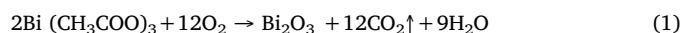


Fig. 3. XRD patterns of Bi-2212 films heat-treated at 600 °C.

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